

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
<b>Thermal Resistance (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RT1	2.6479	530.6127 m	N/A
RT2	11.0629	373.8928 m	N/A
RT3	17.3458	258.2708 m	N/A
RT4	33.9434	337.2237 m	N/A
<b>Thermal Capacitance (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CT1	19.8304 m	30.3158 m	N/A
CT2	100.2958 m	47.8572 m	N/A
CT3	1.5840	81.3467 m	N/A
CT4	2.5767	1.9413 m	N/A

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	2.8491	397.0332 m	N/A
RF2	11.2810	652.9132 m	N/A
RF3	24.7425	237.2455 m	N/A
RF4	26.1274	212.8081 m	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	11.8771 m	1.6962 m	N/A
CF2	64.6191 m	10.9472 m	N/A
CF3	681.7151 m	9.0048 m	N/A
CF4	1.9098	30.3204 m	N/A

**Note**

NA indicates not applicable

